



500.39912CX1

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicants: T. IWASAKI, et al.  
Application No.: 10/611,862  
Filed: July 3, 2003  
For: SEMICONDUCTOR DEVICE WITH MULTILAYER  
CONDUCTIVE STRUCTURE FORMED ON A  
SEMICONDUCTOR SUBSTRATE  
Art Unit: 2813  
Examiner: S. W. Smoot

**AMENDMENT**

Commissioner for Patents  
P.O. BOX 1450  
Alexandria, VA 22313-1450

June 7, 2005

Sir:

In response to the Office Action dated March 7, 2005, please amend the above-identified application as listed below and as set forth on the following pages:

**Amendments to the Claims;**

**Remarks follow the amendments; and**

**Appendix A includes Sworn Translation of Japanese Patent Appln.**

**11-006108, filed January 13, 1999.**